







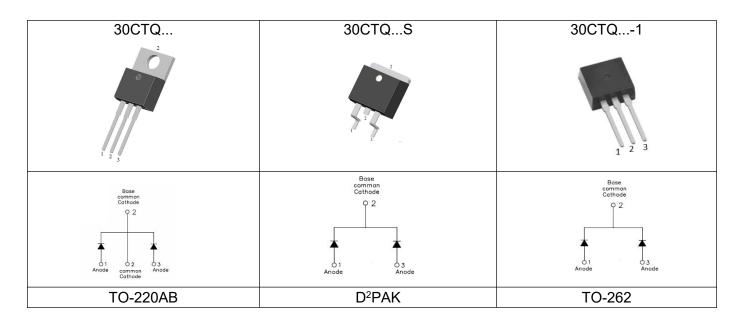
# 30CTQ.../30CTQ...S /30CTQ...-1 SCHOTTKY RECTIFIER

#### **Features**

- 150°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection



#### Maximum Ratings@Tc=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	30(30CTQ030) 35(30CTQ035) 40(30CTQ040) 45(30CTQ045)	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=105°C, rectangular wave form	15(Per Leg) 30(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	318	Α

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30CTQ...S 30CTQ...S

Technical Data Data Sheet N0281, Rev. B





## **Electrical Characteristics:**

Characteristics	Symbol Condition		Тур.	Max.	Units
Forward Voltage Drop	$V_{F1}$	@ 15A, Pulse, T <sub>J</sub> = 25 °C	0.51	0.62	V
(Per Leg)*	$V_{F2}$	@ 15A, Pulse, T <sub>J</sub> = 125 °C	0.45	0.56	V
Reverse Current (Per Leg)*	$I_{R1}$ $@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}\text{C}$		0.05	1.0	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125  ^{\circ}\text{C}$	27	40	mA
Junction Capacitance(Per Leg)	$C_T$ @ $V_R = 5V$ , $T_C = 25$ °C $f_{SIG} = 1MHz$		702	900	pF

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%

# **Thermal-Mechanical Specifications:**

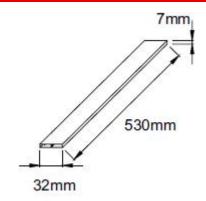
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> JC	DC operation	3.25	°C/W
Typical Thermal Resistance, Case to Heat Sink	R <sub>θJL</sub>	DC operation	0.50	°C/W
Case Style	TO-220AB D <sup>2</sup> PAK TO-262			

## **Tube Specification**

Device	Package	Weight	Shipping
30CTQ	TO-220AB	1.8g	50pcs / tube
30CTQS	D <sup>2</sup> PAK	1.85g	800pcs / reel
30CTQ1	TO-262	1.85g	50pcs / tube

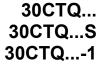
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Tube Specification(TO-220AB/TO-262)**



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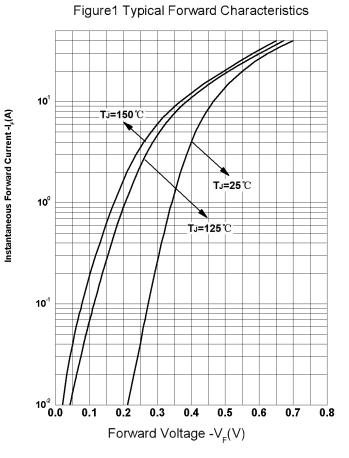


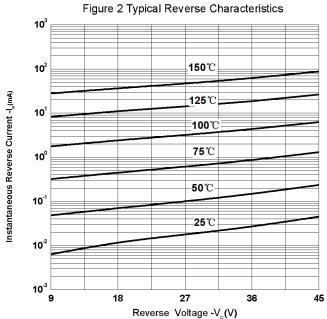


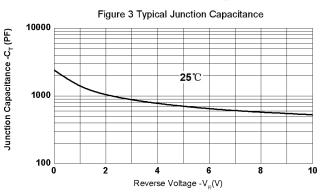




# **Ratings and Characteristics Curves**

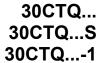






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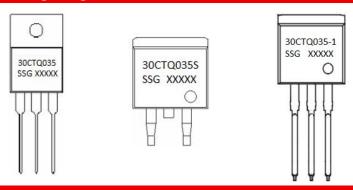








## **Marking Diagram**



#### Where XXXXX is YYWWL

30 = Forward Current (30A)

C = Configuration TQ = Device Type

30/35/40/45 = Reverse Voltage (30V/35V/40V/45V)

S/-1 = Package type

 SSG
 = SSG

 YY
 = Year

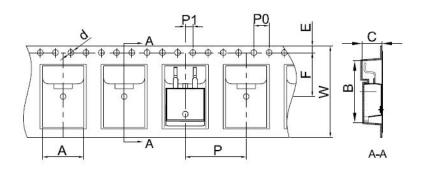
 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

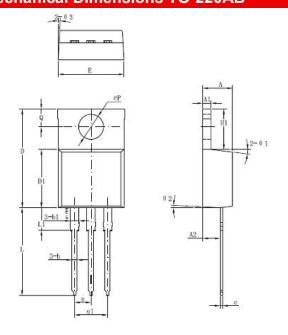
Epoxy resin UL:94V-0

# Carrier Tape Specification D<sup>2</sup>PAK



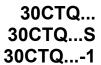
Symbol	Millimeters		
	Min.	Max.	
Α	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

#### **Mechanical Dimensions TO-220AB**



Symbol	Dimensions in millimeters			
	Min	Typical	Max	
Α	3.56	-	4.83	
A1	0.51	-	1.4	
A2	2.03	-	2.92	
b	0.38	-	1.02	
b1	1.14	-	1.78	
С	0.31	-	0.61	
D	14.22	-	16.51	
D1	8.38	-	9.42	
E	9.65	-	10.67	
е	-	2.54	-	
e1	-	5.08	-	
H1	5.84	-	6.86	
L	12.7	-	14.73	
L1	-	-	6.35	
ФР	-	3.56	-	
Q	2.54	-	3.43	

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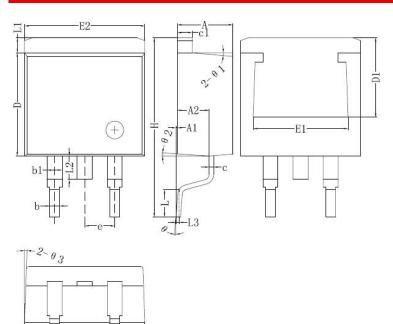






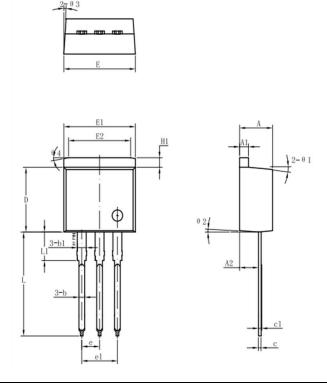


## **Mechanical Dimensions D<sup>2</sup>PAK**



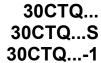
	Dimensions in millimeters		
Symbol	Min.	Max.	
Α	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	9.65	
D1	6.4		
E1	6.22		
E2	9.65	10.67	
е	2.54BSC		
Н	14.6	15.88	
L	1.78	2.8	
L1	-	1.68	
L2	-	2.2	
L3	0.255BSC		
Θ	0	8°	

## **Mechanical Dimensions TO-262**



Comphal	Millimeters				
Symbol	Min.	Typical	Max.		
Α	4.55	4.70	4.85		
A1	1.17	1.27	1.37		
A2	2.59	2.69	2.89		
В	1.22	1.37	1.47		
b	0.71	0.81	0.96		
b1		1.27			
С	0.36	0.38	0.61		
D	8.55	8.70	8.85		
E	10.01	10.16	10.31		
E1	9.88	10.08	10.28		
е		2.54			
e1		5.08			
H1	1.17	1.27	1.37		
L	13.00	13.86	14.08		
L1		3.8			
Θ1		5°			
Θ2		4°			
Θ3		4°			
Θ4		10°			

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